SINGLE OR MULTI CELL LED DRIVER SOLUTION

DESCRIPTION

The ZXSC300 is a single or multi cell LED driver designed for applications where step-up voltage conversion from very low input voltages is required. These applications mainly operate from single 1.5V or 1.2V battery cells. The circuit generates constant current pulses that are ideal for driving single or multiple LED's over a wide range of operating voltages.

The ZXSC300 is a PFM controller IC that drives an external Zetex switching transistor with a very low saturation resistance. These transistors are the best switching devices available for this type of switching conversion enabling high efficiency conversion with input voltages below 1 volt. The drive output of the ZXSC controller generates a dynamic drive signal for the switching transistor.

FEATURES

- 94% efficiency
- Minimum operating input voltage 0.8V
- Fixed output current
- Low saturation voltage switching transistor
- SOT23-5 package

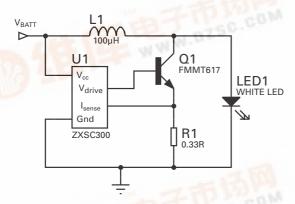
The circuit can start up under full load and operates down to an input voltage of 0.8 volts. The solution configuration ensures optimum efficiency over a wide range of load currents, several circuit configurations are possible depending on battery life versus brightness considerations.

The ZXSC300 is offered in the SOT23-5 package which, when combined with a SOT23 switching transistor, generates a high efficiency small size circuit solution. The IC and discrete combination offers the ultimate cost vs performance solution for single cell LED driving applications.

APPLICATIONS

- · LED flashlights and torches
- LED backlights
- White LED driving
- Multiple LED driving
- Solar Equipment

TYPICAL APPLICATION CIRCUIT



ORDERING INFORMATION

| DEVICE | Reel | Tapewidth | Quantity per reel |
|-------------|------|-----------|----------------------|
| ZXSC300E5TA | 7″ | 8mm | 3,000 |

DEVICE MARKING C300

Package SOT23-5





ABSOLUTE MAXIMUM RATING

Supply Voltage -0.3 to 10V Operating Temperature -40 to 85°C Maximum Voltage Other Pins -0.3 to VCC+0.3V Storage Temperature -55 to 150°C

Power Dissipation 450mW

ELECTRICAL CHARACTERISTICS: Test conditions unless otherwise stated: V_{CC}=1.5V, T_{AMB}=25°C

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|---------------------------------|--------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|------|-----------------|-------|
| η | Efficiency ¹ | | | | 94 | % |
| V _{CC} | Recommended supply voltage range | | 0.8 | | 8 | V |
| V _{CC(min)} | Minimum startup and operating voltage | I _{DRIVE} =-600μA, V _{DRIVE} =0.7V I _{DRIVE} =-600μA, V _{DRIVE} =0.7V, T _{AMB} =-10°C ³ | | 0.8 | 0.92 | V |
| Iα | Quiescent current ² | | | 0.2 | | mA |
| I _{VDRIVE} | Base drive current | V _{DRIVE} = 0.7V, V _{ISENSE} = 0V | 1.5 | | 3.6 | mA |
| I _{CC} | Supply current ³ | V _{DRIVE} = 0.7V, V _{ISENSE} = 0V | 2 | | 4 | mA |
| V _{VDRIVE(high)} | High level drive voltage | V _{ISENSE} = 0V, I _{VDRIVE} =-0.5mA | V _{CC} -0.3 | | V _{CC} | V |
| V _{VDRIVE(Iow)} | Low level drive voltage | V _{ISENSE} = 50mV, I _{VDRIVE} = 5mA | 0 | | 0.2 | V |
| V _{ISENSE} (threshold) | Output current reference voltage | | 14 | 19 | 24 | mV |
| T _{CVISENSE} | I _{SENSE} voltage temp co. ² | | | 0.4 | | %/°C |
| I _{ISENSE} | I _{SENSE} input current | V _{ISENSE} = 0V | 0 | -30 | -65 | μΑ |
| T _{DRV} | Discharge pulse width | | 1.2 | 1.7 | 3.2 | μs |

OPERATING CONDITIONS

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|--------|----------------------------------------------|------------|------|------|------|-------|
| Fosc | Recommended operating frequency ⁴ | | | | 200 | kHz |



 $^{^{1}}_{2}$ Application dependent, see reference designs. These parameters guaranteed by design and characterisation $^{3}_{4}$ Total supply current =I_Q + I_VDRIVE, see typical characteristics $^{4}_{4}$ Operating frequency is application circuit dependent. See applications section.

FMMT617

For the circuits described in the applications section, Zetex FMMT617 is the recommended pass transistor. The following indicates outline data for the transistor, more detailed information can be found in the Zetex surface mount data book or at www.zetex.com

ELECTRICAL CHARACTERISTICS (at $T_{\Delta} = 25^{\circ}\text{C}$ unless otherwise stated).

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS | |
|-----------------------------------------|----------------------|------|----------------|------------------|----------------|---------------------------------------------------------------------------------------------------------------------------------------|--|
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | | 8 70 150 | 14 100 200 | mV mV mV | I _C =0.1A, I _B =10mA* I _C =1A, I _B =10mA* I _C =3A, I _B =40mA* | |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | 15 | 18 | | V | I _C =10mA* | |

^{*}Measured under pulsed conditions. Pulse width=300µs. Duty cycle ≤ 2%

ZHCS1000

For the circuits described in the applications section Zetex ZHCS1000 is the recommended Schottky diode. The following indicates outline data for the diode, more detailed information is available at www.zetex.com

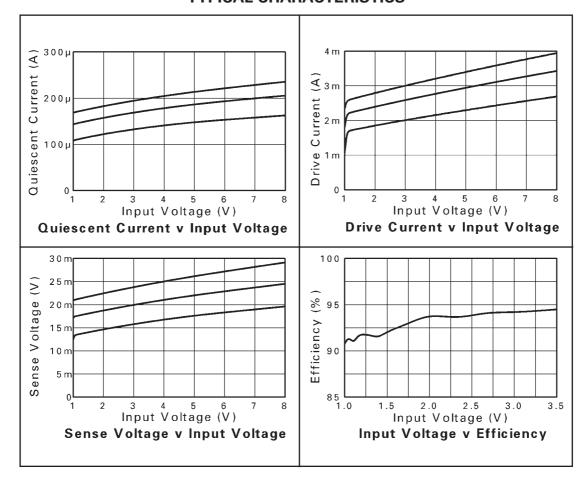
ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C unless otherwise stated).

| amb — comment of the | | | | | | | |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|------|------|------------|----------|-------------------------------------------------------------------------------------------------|--|
| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS | |
| Forward Voltage | V _F | | | 400 500 | mV mV | I _F =500mA I _F =1A | |
| Reverse Current | I _R | | 50 | 100 | μА | V _R =30V | |
| Reverse Recovery Time | t _{rr} | | 12 | | ns | Switched from $I_F = 500 \text{mA}$ to $I_R = 500 \text{mA}$. Measured at $I_R = 50 \text{mA}$ | |

^{*}Measured under pulsed conditions. Pulse width=300 μ s. Duty cycle $\leq~2\%$



TYPICAL CHARACTERISTICS





DEVICE DESCRIPTION

The ZXSC300 is PFM, controller IC which, when combined with a high performance external transistor, enables the production of a high efficiency boost converter for use in single cell LED driving applications. A block diagram is shown for the ZXSC300 in Figure 1.

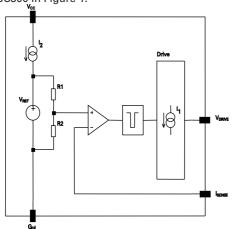


Figure 1 ZXSC300 Block Diagram

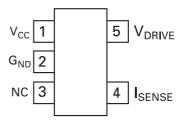
The on chip comparator forces the driver circuit and therefore the external switching transistor off if the voltage at I_{SENSE} exceeds 19mV. This threshold is set by an internal reference circuit and divider.

The Voltage at I_{SENSE} is taken from a current sense resistor connected in series with the emitter of the switching transistor. A monostable following the output of the comparator forces the turn-off time of the output stage to be typically 1.7µs. This ensures that there is sufficient time to discharge the inductor coil before the next on period.

With every on pulse the switching transistor is kept on until the voltage across the current-sense resistor exceeds the threshold of the Isense input. The on-pulse length, and therefore the switching frequency, is determined by the programmed peak current, the input voltage and the input to output voltage differential. See applications section for details.

The Driver circuit supplies the external switching transistor with a fixed drive current. To maximise efficiency the external transistor switched quickly, typically being forced off within 30ns.

Pinout Diagram



Pin Descriptions

| Pin No. | Name | Description |
|---------|--------------------|-------------------------------------------------------------------------------------------------------|
| 1 | V _{CC} | Supply voltage, generally Alkaline, NiMH or NiCd single cell |
| 2 | Gnd | Ground |
| 3 | N/C | Not connected |
| 4 | I _{SENSE} | Inductor current sense input. Internal threshold voltage set to 19mV. Connect external sense resistor |
| 5 | V _{DRIVE} | Drive output for external switching transistor. Connect to base of external switching transistor |

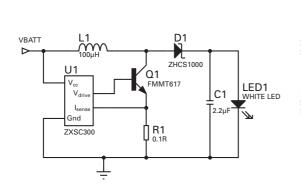


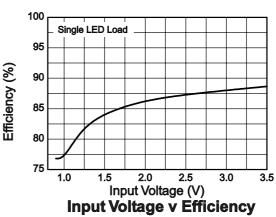
REFERENCE DESIGNS

Two typical LED driving applications are shown. Firstly a maximum brightness solution and secondly an optimised battery life solution.

Maximum brightness solution

This circuit provides a constant current output to the LED by rectifying the switching pulses. This ensures maximum LED brightness.





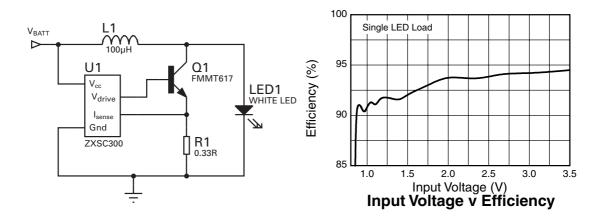
Material List

| Ref | Value | Part Number | Manufacture | Comments |
|------|---------|-------------|-----------------------------------------------|--------------------------------|
| U1 | N/A | ZXSC300E5 | Zetex Plc | Single cell converter, SOT23-5 |
| Q1 | N/A | FMMT617 | Zetex Plc Low V _{CE(sat)} NPN, SOT23 | |
| D1 | 1A | ZHCS1000 | Zetex Plc | 1A Shottky diode, SOT23 |
| R1 | 100mW | Generic | Various | 0805 Size |
| C1 | 2.2mF | Generic | Various | Low ESR ceramic capacitor |
| L1 | 100µH | DO1608P-104 | Coilcraft | Surface mount inductor |
| LED1 | 5600mcd | NSPW500BS | Nichia | White LED |



Maximum battery life solution

To ensure optimum efficiency, and therefore maximum battery life, the LED is supplied with a pulsed current. Maximum efficiency is ensured with the removal of rectifier losses experienced in the maximum brightness solution.



Materials list

| Ref | Value | Part Number | Manufacture | Comments |
|------|---------|-------------|-------------|-------------------------------------|
| U1 | N/A | ZXSC300E5 | Zetex Plc | Single cell converter, SOT23-5 |
| Q1 | N/A | FMMT617 | Zetex Plc | Low V _{CE(SAT)} NPN, SOT23 |
| R1 | 330mW | Generic | Various | 0805 Size |
| L1 | 100mH | DO1608P-104 | Coilcraft | Surface mount inductor |
| LED1 | 5600mcd | NSPW500BS | Nichia | White LED |

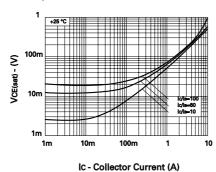


APPLICATIONS INFORMATION

The following section is a design guide for optimum converter performance.

Switching transistor selection

The choice of switching transistor has a major impact on the converter efficiency. For optimum performance, a bipolar transistor with low $V_{\text{CE}(\text{SAT})}$ and high gain is required.



V_{CE(SAT)} v IC



For the maximum battery life solution a Schottky rectifier diode is required. As with the switching transistor the Schottky rectifier diode has a major impact on the converter efficiency. A Schottky diode with a low forward voltage and fast recovery time should be used for this application.

The diode should be selected so that the maximum forward current is greater or equal to the maximum peak current in the inductor, and the maximum reverse voltage is greater or equal to the output voltage.

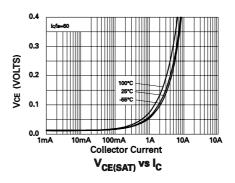
The Zetex ZHCS1000 meets these needs. Datasheets for the ZHCS Series are available on Zetex web site or through your local Zetex sales office. Outline information is included in the characteristics section of this data sheet.

For the maximum brightness solution a pulsed current is supplied to the LED therefore a Schottky rectifier diode is not required.

Inductor selection

The inductor value must be chosen to satisfy performance, cost and size requirements of the overall solution. For the reference designs we recommend an inductor value of 100uH with a core saturation current rating greater than the converter peak current value and low series resistance.

The Zetex FMMT617 is an ideal choice of transistor, having a low saturation voltage. A data sheet for the FMMT617 is available on Zetex web site or through your local Zetex sales office. Outline information is included in the characteristics section of this data sheet.



Inductor selection has a significant impact on the converter performance. For applications where efficiency is critical, an inductor with a series resistance of $500 m\Omega$ or less should be used.

Peak current definition

The peak current rating is a design parameter whose value is dependent upon the overall application. For the high brightness reference designs, a peak current of was chosen to ensure that the converter could provide the required output power to the LED.

In general, the l_{PK} value must be chosen to ensure that the switching transistor, Q1, is in full saturation with maximum output power conditions, assuming worse-case input voltage and transistor gain under all operating temperature extremes.

Once $I_{\mbox{\footnotesize{PK}}}$ is decided the value of $R_{\mbox{\footnotesize{SENSE}}}$ can be determined by:

$$R_{\text{SENSE}} = \frac{V_{\text{ISENSE}}}{I_{\text{PK}}}$$

where V_{ISENSE}=19mV



Output Power Calculation

By making the above assumptions for inductance and peak current the output power can be determined by:

$$P_{\text{OUT}} = \frac{\left(V_{\text{OUT}}, V_{\text{IN}}\right) x \left(I_{\text{PK}} + I_{\text{MIN}}\right)}{2} x \frac{T_{\text{OFF}}}{\left(T_{\text{ON}} + T_{\text{OFF}}\right)}$$

Note: $V_{OUT} = output \ voltage + Schottky \ rectifier \ voltage \ drop$

where

 $T_{OFF}\cong 1.7 \mu s$ (internally set by ZXSC300)

and

$$T_{\text{ON}} = \frac{T_{\text{OFF}}(V_{\text{OUT}} - V_{\text{IN}})}{V_{\text{IN}}}$$

and

$$I_{MIN} = I_{PK} - \frac{(V_{OUT} - V_{IN}) \times T_{OFF}}{L}$$

Operating frequency can be derived by:

$$F = \frac{1}{(T_{ON} + T_{OFF})}$$

Capacitor selection

For pulsed operation, as in the maximum battery life solution, no capacitors are required at the output to the LED. For rectified operation, as in the maximum brightness solution, a small value ceramic capacitor is required, typically 2.2uF.

Generally an input capacitor is not required, but a small ceramic capacitor may be added to aid EMC, typically 470nF to 1uF.

Demonstration board

A demonstration board for the Maximum battery life solution, is available upon request. These can be obtained through your local Zetex office or through Zetex web pages. For all reference designs Gerber files and bill of materials can be supplied.

Layout of Maximum battery life solution

Top Copper



Drill Holes



Bottom Copper



Silk Screen



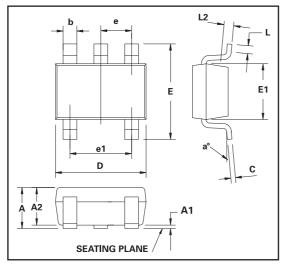


SUPPLIER LISTING

| Manufacturer | EUROPE | ASIA | USA | | |
|--------------------|---------------------------------------|-----------------------------|-----------------------------------------------------------------|--|--|
| Zetex | Zetex GmbH Germany | Zetex Asia Hong Kong | Zetex Inc | | |
| Tel: | (49) 894549490 | (852) 2610 0611 | (1) 631 543 7100 | | |
| URL: | | http://www.zetex.com | 1 | | |
| AVX | AVX UK | AVX Asia Singapore | AVX USA | | |
| Tel: | (44) 1252 770000 | (65) 6286 7555 | (1) 843 448 9411 | | |
| URL: | | http://www.avxcorp.co | m | | |
| Coilcraft | Coilcraft Europe UK | | Coilcraft Inc | | |
| Tel: | (44) 1236 730595 | | (1) 847 639 6400 | | |
| URL: | | http://www.coilcraft.co | om | | |
| Nichia Corporation | Nichia Europe B.V. The Netherlands | Nichia Corporation Japan | Nichia America Corporation | | |
| Tel: | (31) 20 5060900 | (81) 3 3456 3784 | Head Office (1) 717 285 2323 San Jose (1) 408 573 0933 | | |
| URL: | http://www.nichia.co.jp | | | | |



PACKAGE OUTLINE



PACKAGE DIMENSIONS

| DIM | Millin | neters | Inches | | |
|-------|--------|--------|--------|--------|--|
| DIIVI | MIN. | MAX. | MIN. | MAX. | |
| А | 0.90 | 1.45 | 0.0354 | 0.0570 | |
| A1 | - | 0.15 | - | 0.0059 | |
| A2 | 0.90 | 1.30 | 0.0354 | 0.0511 | |
| b | 0.20 | 0.50 | 0.0078 | 0.0196 | |
| С | 0.09 | 0.26 | 0.0035 | 0.0102 | |
| D | 2.70 | 3.10 | 0.1062 | 0.1220 | |
| Е | 2.20 | 3.20 | 0.0866 | 0.1181 | |
| E1 | 1.30 | 1.80 | 0.0511 | 0.0708 | |
| е | 0.95 | REF | 0.037 | 4 REF | |
| e1 | 1.90 | REF | 0.074 | 8 REF | |
| L | 0.10 | 0.60 | 0.0039 | 0.0236 | |
| а | 0° | 30° | 0° | 30° | |



Definitions

Product change

Zetex Semiconductors reserves the right to alter, without notice, specifications, design, price or conditions of supply of any product or service.

Customers are solely responsible for obtaining the latest relevant information before placing orders.

Applications disclaimer
The circuits in this design/application note are offered as design ideas. It is the responsibility of the user to ensure that the circuit is fit for the user's application and meets with the user's requirements. No representation or warranty is given and no liability whatsoever is assumed by Zetex with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Zetex does not assume any legal responsibility or will not be held legally liable (whether in contract, tort (including negligence), breach of statutory duty, restriction or otherwise) for any damages, loss of profit, business, contract, opportunity or consequential loss in the use of these circuit applications, under any circumstances.

Life support
Zetex products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Zetex Semiconductors plc. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body

or

support or sustain life and whose failure to perform when properly used in accordance with instructions
for use provided in the labeling can be reasonably expected to result in significant injury to the user.
 A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of
the life support device or to affect its safety or effectiveness.

The product specifications contained in this publication are issued to provide outline information only which (unless agreed by the company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contract or be regarded as a representation relating to the products or services concerned.

Terms and Conditions

All products are sold subjects to Zetex' terms and conditions of sale, and this disclaimer (save in the event of a conflict between the two when the terms of the contract shall prevail) according to region, supplied at the time of order acknowledgement.

For the latest information on technology, delivery terms and conditions and prices, please contact your nearest Zetex sales office or visit; www.zetex.com

Quality of product Zetex is an ISO 9001 and TS16949 certified semiconductor manufacturer.

To ensure quality of service and products we strongly advise the purchase of parts directly from Zetex Semiconductors or one of our regionally authorized distributors. For a complete listing of authorized distributors please visit: www.zetex.com/salesnetwork

Zetex Semiconductors does not warrant or accept any liability whatsoever in respect of any parts purchased through unauthorized sales channels.

ESD (Electrostatic discharge)

Semiconductor devices are susceptible to damage by ESD. Suitable precautions should be taken when handling and transporting devices. The possible damage to devices depends on the circumstances of the handling and transporting, and the nature of the device. The extent of damage can vary from immediate functional or parametric malfunction to degradation of function or performance in use over time. Devices suspected of being affected should be replaced

Green compliance

Zetex Semiconductors is committed to environmental excellence in all aspects of its operations which includes meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Zetex components are compliant with the RoHS directive, and through this it is supporting its customers in their compliance with WEEE and ELV

directives

Product status key:

Future device intended for production at some point. Samples may be available

"Active" Product status recommended for new designs

"Last time buy (LTB)" Device will be discontinued and last time buy period and delivery is in effect

"Not recommended for new designs" Device is still in production to support existing designs and production

Production has been discontinued "Obsolete'

Datasheet status key: "Draft version"

"Issue

This term denotes a very early datasheet version and contains highly provisional information, which may change in any

This term denotes a pre-release datasheet. It provides a clear indication of anticipated performance. However, changes to the test conditions and specifications may occur, at any time and without notice. "Provisional version"

This term denotes an issued datasheet containing finalized specifications. However, changes to specifications may occur, at any time and without notice.

© Zetex Semiconductors plc 2006

Europe Asia Pacific Corporate Headquarters Americas Zetex GmbH Zetex (Asia) Ltd Zetex Semiconductors plc Zetex Inc 3701-04 Metroplaza Tower 1 Hing Fong Road, Kwai Fong Zetex Technology Park Chadderton, Oldham, OL9 9LL Kustermann-Park 700 Veterans Memorial Hwv Balanstraße 59 Hauppauge, NY 11788 D-81673 München USA Hong Kong United Kinadom Germany Telefon: (49) 89 45 49 49 0 Telephone: (1) 631 360 2222 Telephone: (852) 26100 611 Telephone (44) 161 622 4444 Fax: (49) 89 45 49 49 49 Fax: (1) 631 360 8222 Fax: (852) 24250 494 Fax: (44) 161 622 4446 usa.sales@zetex.com asia.sales@zetex.com hq@zetex.com

